

## P-Channel 40 V (D-S) MOSFET

### PRODUCT SUMMARY

| V <sub>DS</sub> (V) | R <sub>DS(on)</sub> (Ω)            | I <sub>D</sub> (A) |
|---------------------|------------------------------------|--------------------|
| - 40                | 0.0096 at V <sub>GS</sub> = - 10 V | - 70 <sup>d</sup>  |
|                     | 0.012 at V <sub>GS</sub> = - 4.5 V | -60 <sup>d</sup>   |

### FEATURES

- DT-Trench Power MOSFET
- 100 % Rg and UIS Tested

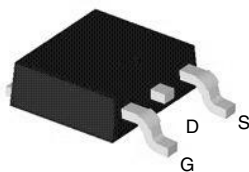


**RoHS**  
COMPLIANT

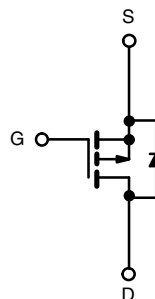
### APPLICATIONS

- Load Switch

TO-252 Pin Configuration



Top View



P-Channel MOSFET

### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25 °C, unless otherwise noted)

| Parameter  | Symbol                            | Limit                   | Unit                |    |
|--|-----------------------------------|-------------------------|---------------------|----|
| Drain-Source Voltage                               | V <sub>DS</sub>                   | - 40                    | V                   |    |
| Gate-Source Voltage                                | V <sub>GS</sub>                   | ± 20                    |                     |    |
| Continuous Drain Current (T <sub>J</sub> = 175 °C) | I <sub>D</sub>                    | T <sub>C</sub> = 25 °C  | - 70 <sup>d</sup>   |    |
|  |                                   | T <sub>C</sub> = 125 °C | - 41                |    |
| Pulsed Drain Current                               | I <sub>DM</sub>                   | - 280                   | A                   |    |
| Avalanche Current                                  | I <sub>AR</sub>                   | - 63                    |                     |    |
| Repetitive Avalanche Energy <sup>a</sup>           | L = 0.1 mH                        | E <sub>AR</sub>         | 125                 | mJ |
| Power Dissipation                                  | P <sub>D</sub>                    | T <sub>C</sub> = 25 °C  | 88 <sup>c</sup>     | W  |
|  |                                   | T <sub>A</sub> = 25 °C  | 2.9 <sup>b, c</sup> |    |
| Operating Junction and Storage Temperature Range   | T <sub>J</sub> , T <sub>stg</sub> | - 55 to 150             | °C                  |    |

### THERMAL RESISTANCE RATINGS

| Parameter                        | Symbol            | Typical      | Maximum | Unit |
|----------------------------------|-------------------|--------------|---------|------|
| Junction-to-Ambient <sup>b</sup> | R <sub>thJA</sub> | t ≤ 10 s     | 20      | 30   |
|                                  |                   | Steady State | 40      | 60   |
| Junction-to-Case                 | R <sub>thJC</sub> | -            | 2.1     | °C/W |

Notes:

- Duty cycle ≤ 1 %.
- When mounted on 1" square PCB (FR-4 material).
- See SOA curve for voltage derating.
- Package limited.

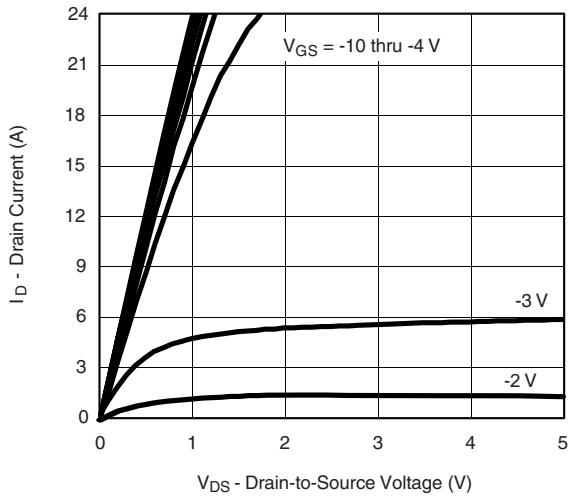
| <b>SPECIFICATIONS</b> ( $T_J = 25\text{ }^\circ\text{C}$ , unless otherwise noted)       |              |  |      |        |           |               |
|--|--------------|--|------|--------|-----------|---------------|
| Parameter  | Symbol       | Test Conditions  | Min. | Typ.   | Max.      | Unit          |
| <b>Static</b>  |              |  |      |        |           |               |
| Drain-Source Breakdown Voltage   | $V_{DS}$     | $V_{GS} = 0\text{ V}, I_D = -250\text{ }\mu\text{A}$   | - 40 |        |           | V             |
| Gate Threshold Voltage   | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D = -250\text{ }\mu\text{A}$   | - 1  |        | - 3       |               |
| Gate-Body Leakage  | $I_{GSS}$    | $V_{DS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$  |      |        | $\pm 100$ | nA            |
| Zero Gate Voltage Drain Current  | $I_{DSS}$    | $V_{DS} = -40\text{ V}, V_{GS} = 0\text{ V}$   |      |        | - 1       | $\mu\text{A}$ |
|  |              | $V_{DS} = -32\text{ V}, V_{GS} = 0\text{ V}, T_J = 125\text{ }^\circ\text{C}$  |      |        | - 50      |               |
|  |              | $V_{DS} = -32\text{ V}, V_{GS} = 0\text{ V}, T_J = 150\text{ }^\circ\text{C}$  |      |        | - 100     |               |
| On-State Drain Current <sup>a</sup>  | $I_{D(on)}$  | $V_{DS} = -5\text{ V}, V_{GS} = -10\text{ V}$  | - 70 |        |           | A             |
| Drain-Source On-State Resistance <sup>a</sup>  | $R_{DS(on)}$ | $V_{GS} = -10\text{ V}, I_D = -30\text{ A}$  |      | 0.0096 | 0.0125    | $\Omega$      |
|  |              | $V_{GS} = -4.5\text{ V}, I_D = -20\text{ A}$   |      | 0.012  | 0.016     |               |
| Forward Transconductance <sup>a</sup>  | $g_{fs}$     | $V_{DS} = -15\text{ V}, I_D = -30\text{ A}$  |      | 66     |           | S             |
| <b>Dynamic<sup>b</sup></b>   |              |  |      |        |           |               |
| Input Capacitance  | $C_{iss}$    | $V_{GS} = 0\text{ V}, V_{DS} = -20\text{ V}, f = 1\text{ MHz}$   |      | 4910   |           | pF            |
| Output Capacitance   | $C_{oss}$    |  |      | 392    |           |               |
| Reverse Transfer Capacitance   | $C_{rss}$    |  |      | 103    |           |               |
| Total Gate Charge <sup>c</sup>   | $Q_g$        | $V_{DS} = -20\text{ V}, V_{GS} = -10\text{ V}, I_D = -30\text{ A}$   |      | 55     |           | nC            |
| Gate-Source Charge <sup>c</sup>  | $Q_{gs}$     |  |      | 21     |           |               |
| Gate-Drain Charge <sup>c</sup>   | $Q_{gd}$     |  |      | 7      |           |               |
| Turn-On Delay Time <sup>c</sup>  | $t_{d(on)}$  | $V_{DD} = -20\text{ V}, R_L = 0.6\text{ }\Omega$<br>$I_D \cong -5\text{ A}, V_{GEN} = -10\text{ V}, R_G = 6\text{ }\Omega$ |      | 10     |           | ns            |
| Rise Time <sup>c</sup>   | $t_r$        |  |      | 30     |           |               |
| Turn-Off Delay Time <sup>c</sup>   | $t_{d(off)}$ |  |      | 62     |           |               |
| Fall Time <sup>c</sup>   | $t_f$        |  |      | 22     |           |               |
| <b>Source-Drain Diode Ratings and Characteristics</b> $T_C = 25\text{ }^\circ\text{C}^b$ |              |  |      |        |           |               |
| Continuous Current   | $I_S$        |  |      |        | - 55      | A             |
| Forward Voltage <sup>a</sup>   | $V_{SD}$     | $I_F = -1\text{ A}, V_{GS} = 0\text{ V}$   |      | - 0.7  | - 1.2     | V             |
| Reverse Recovery Time  | $t_{rr}$     | $I_F = -10\text{ A}, dI/dt = 100\text{ A}/\mu\text{s}$   |      | 39     |           | ns            |
| Reverse Recovery Charge  | $Q_{rr}$     | $I_F = -10\text{ A}, dI/dt = 100\text{ A}/\mu\text{s}$   |      | 47     |           | nC            |

Notes:

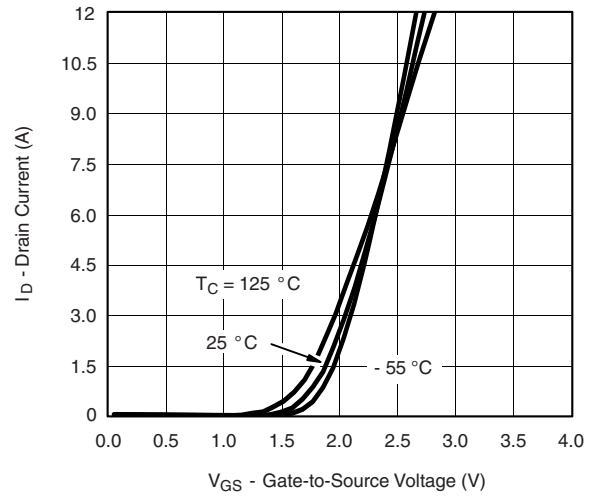
- Pulse test; pulse width  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$ .
- Guaranteed by design, not subject to production testing.
- Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

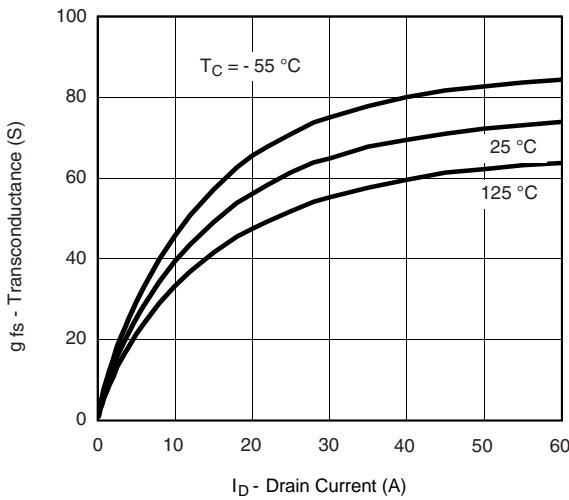
**TYPICAL CHARACTERISTICS** (25 °C, unless otherwise noted)



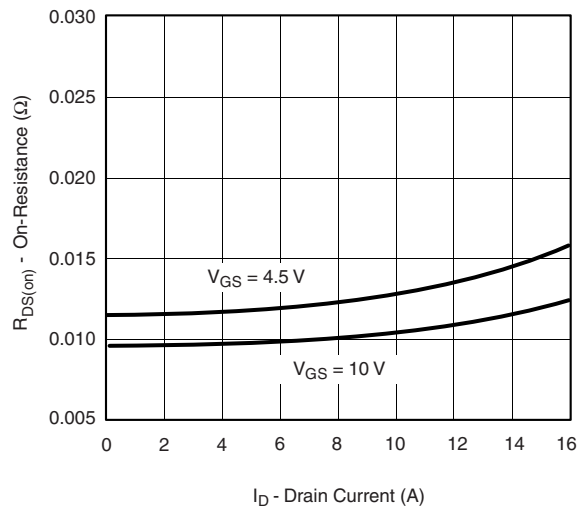
**Output Characteristics**



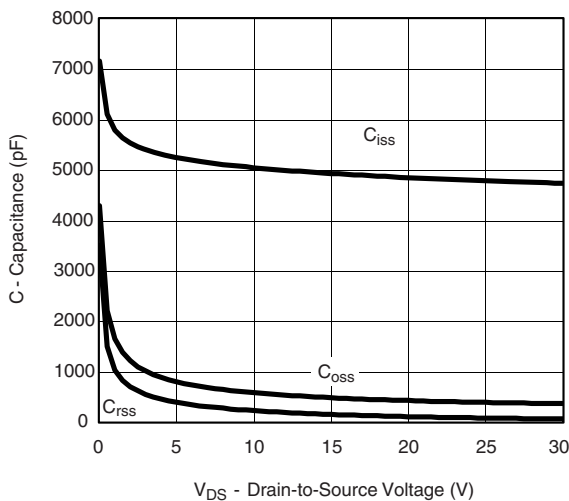
**Transfer Characteristics**



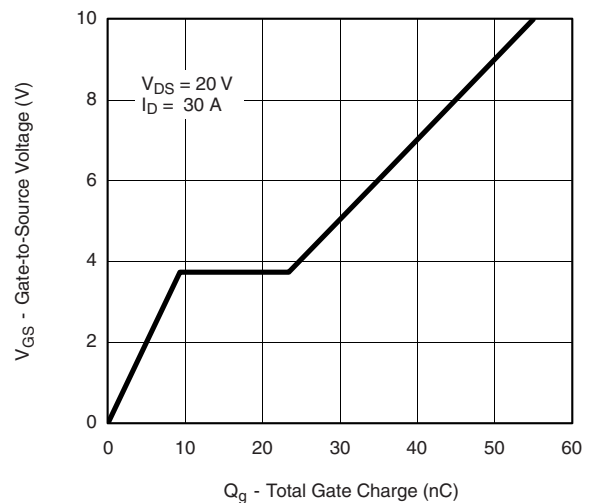
**Transconductance**



**On-Resistance vs. Drain Current**

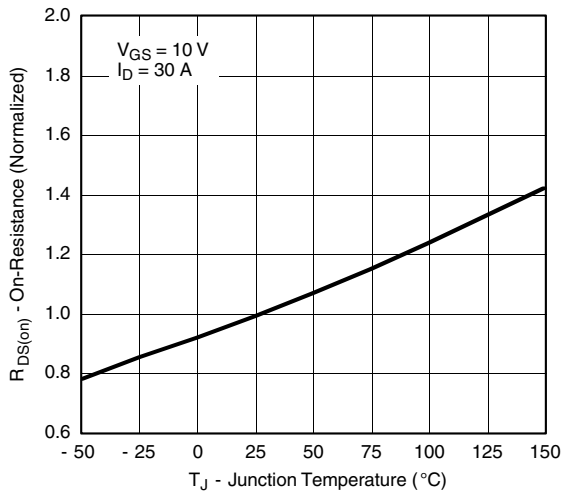


**Capacitance**

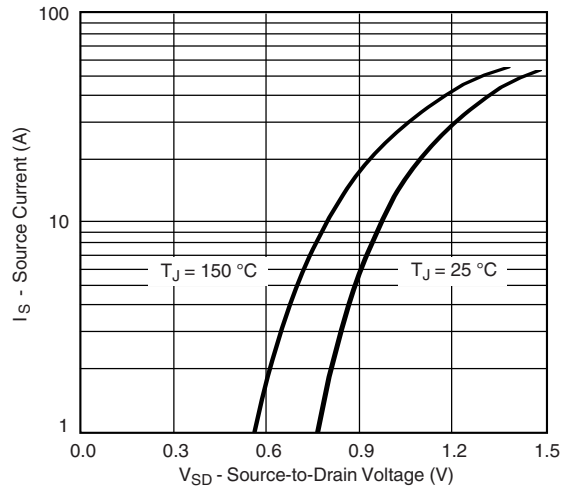


**Gate Charge**

**TYPICAL CHARACTERISTICS**

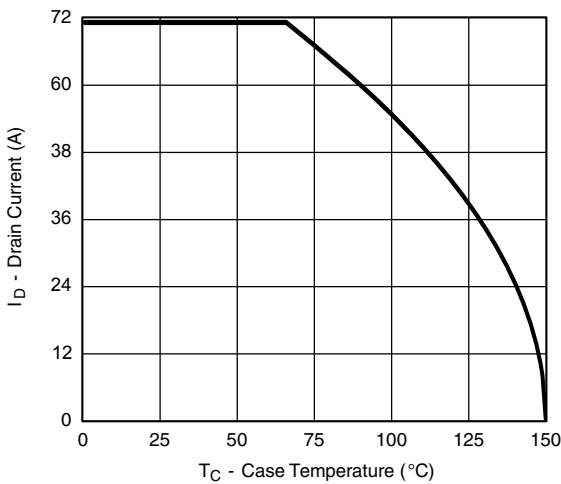


On-Resistance vs. Junction Temperature

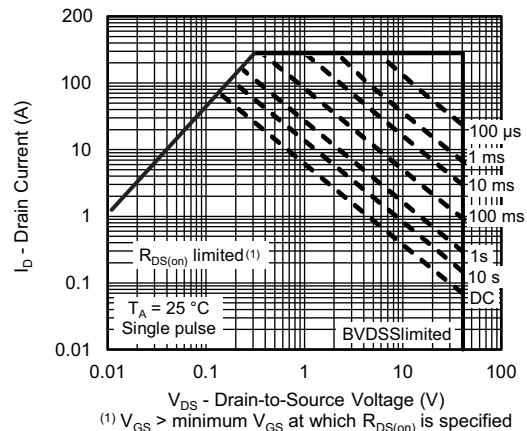


Source-Drain Diode Forward Voltage

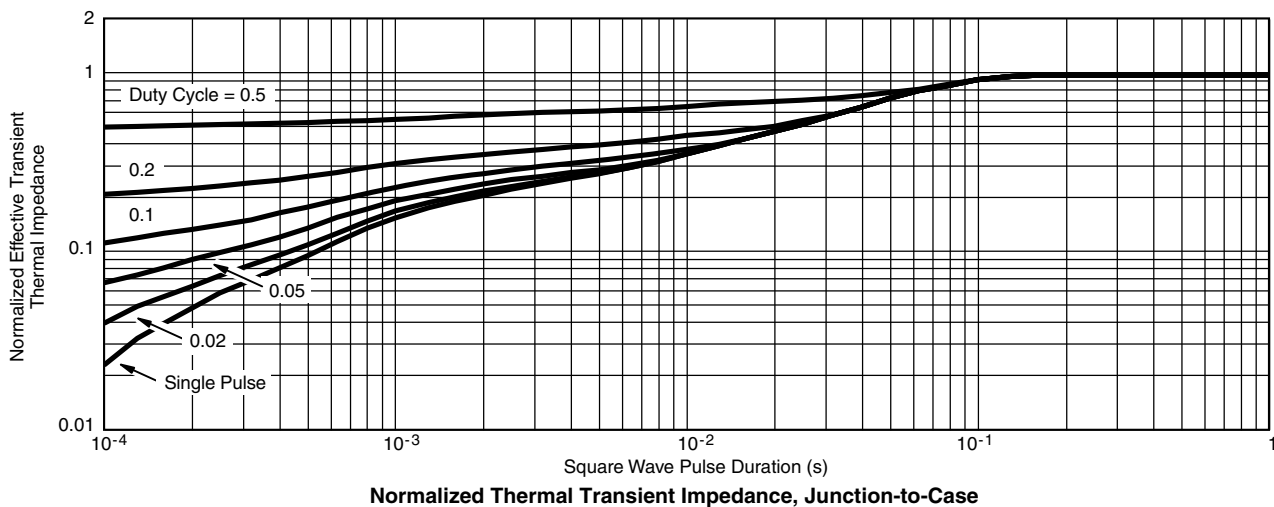
**THERMAL RATINGS** (25 °C, unless otherwise noted)



Drain Current vs. Case Temperature

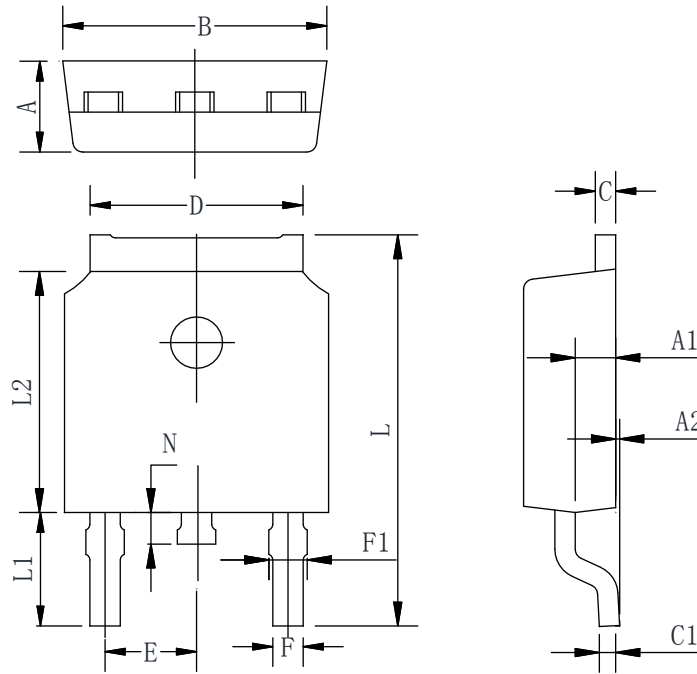


Safe Operating Area, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

## TO-252-2L PACKAGE OUTLINE



COMMON DIMENSIONS  
(UNITS OF MEASURE=MILLIMETER)

| Symbol | Min       | Typ  | Max   |
|--------|-----------|------|-------|
| A      | 2.10      | 2.30 | 2.50  |
| A1     | 0.88      | 1.01 | 1.16  |
| A2     | 0.00      | 0.15 | 0.28  |
| B      | 6.40      | 6.60 | 6.80  |
| C      | 0.42      | 0.50 | 0.63  |
| C1     | 0.42      | 0.50 | 0.63  |
| D      | 5.08      | 5.32 | 5.65  |
| E      | 2.286 TYP |      |       |
| F      | 0.63      | 0.76 | 0.89  |
| F1     | 0.64      | 0.86 | 1.08  |
| L      | 9.30      | 9.90 | 10.80 |
| L1     | 2.4       | 2.8  | 3.6   |
| L2     | 5.90      | 6.10 | 6.55  |
| N      | 0.57      | 0.80 | 1.05  |

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